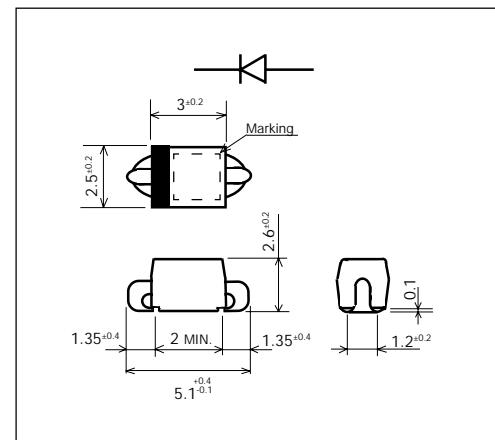


SCHOTTKY BARRIER DIODE

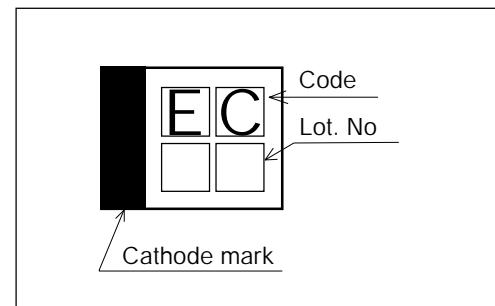
■ Outline drawings, mm



■ Features

- Surface-mount device
- Low VF
- Super high speed switching
- High reliability by planer design

■ Marking



■ Applications

- High speed switching

■ Maximum ratings and characteristics

- Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}		60	V
Non-repetitive peak reverse voltage	V _{RSM}	t _w =500ns, duty=1/40	60	V
Average output current	I _O	Resistive load T _J =111°C	1.0*	A
Surge current	I _{FSM}	Sine wave 10ms	30	A
Operating junction temperature	T _J		-40 to +150	°C
Storage temperature	T _{stg}		-40 to +150	°C

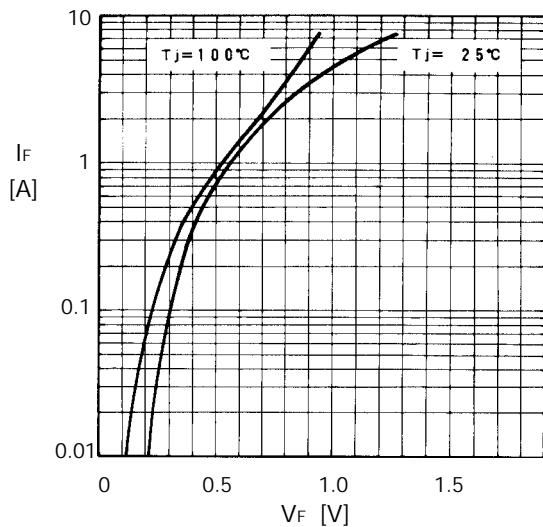
* Mounted on printed circuit board (15 x 15mm)

- Electrical characteristics (Ta=25°C Unless otherwise specified)

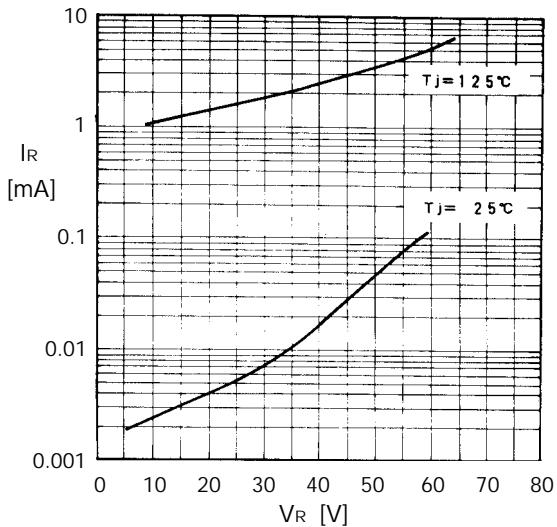
Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V _{FM}	I _{FM} =1A	0.58	V
Reverse current	I _{RRM}	V _R =V _{RRM}	2.0	mA
Thermal resistance	R _{th(j-l)}	Junction to lead	15*	°C/W

■ Characteristics

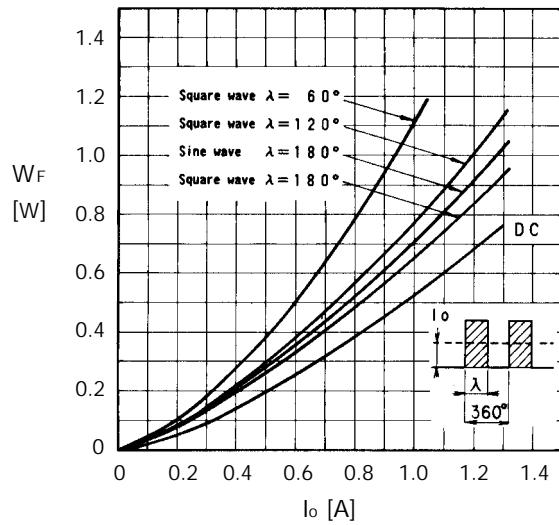
Forward characteristics



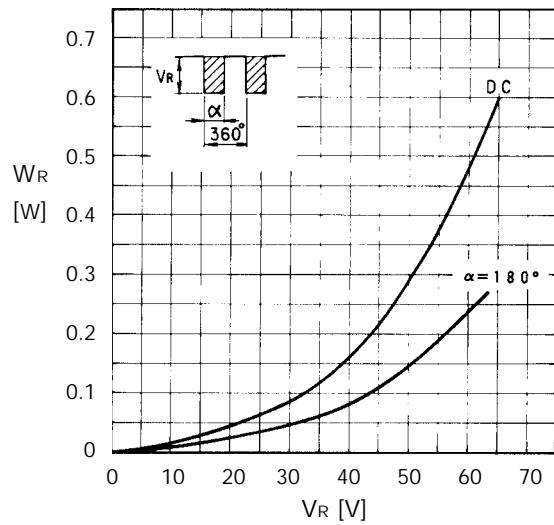
Reverse characteristics



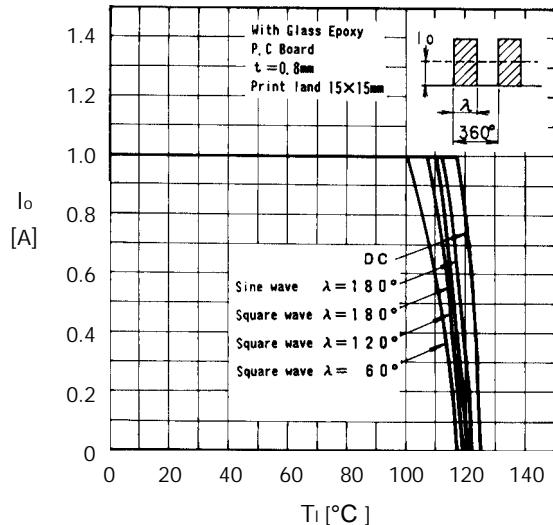
Forward power dissipation



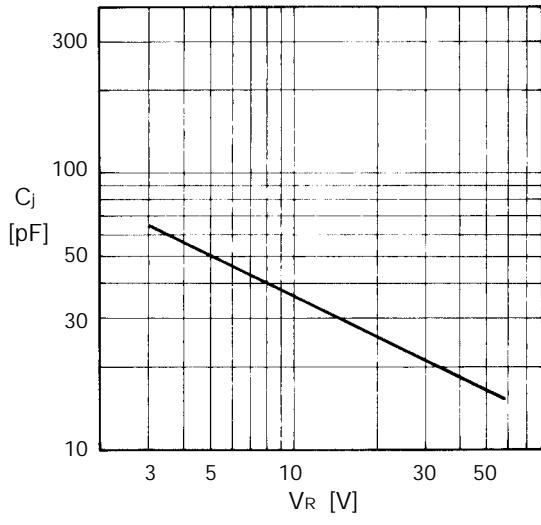
Reverse power dissipation



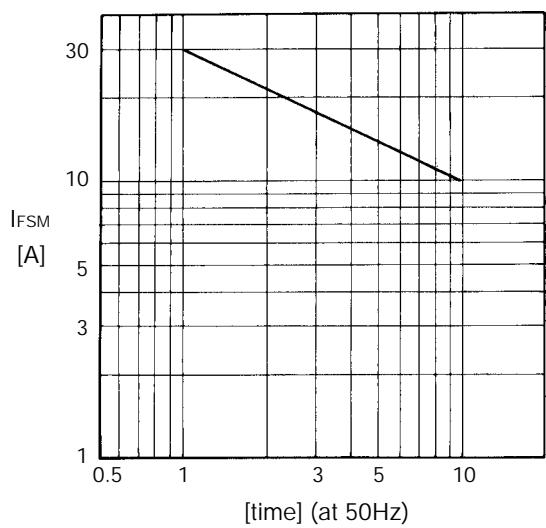
Current derating ($I_o - T_j$)



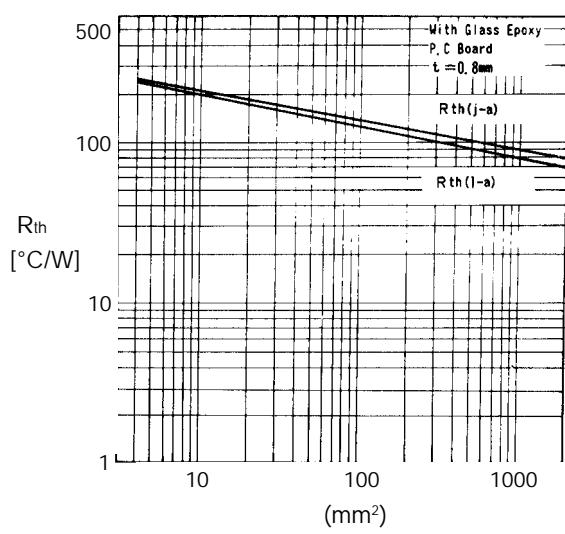
Junction capacitance characteristics



Surge capability



Thermal resistance print land



Transient thermal impedance

